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January 2009

FDD6778A

N-Channel PowerTrench $^{\! \rm I\!R}$ MOSFET 25 V, 14.0 m Ω

Features

- Max $r_{DS(on)}$ = 14.0 m Ω at V_{GS} = 10 V, I_D = 10.0 A
- Max $r_{DS(on)}$ = 30.0 m Ω at V_{GS} = 4.5 V, I_D = 9.7 A
- 100% UIL tested
- RoHS Compliant

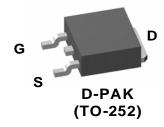


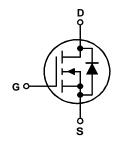
General Description

This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $r_{DS(on)}$ and fast switching speed.

Applications

- Vcore DC-DC for Desktop Computers and Servers
- VRM for Intermediate Bus Architecture





MOSFET Maximum Ratings T_C = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units
V_{DS}	Drain to Source Voltage			25	V
V _{GS}	Gate to Source Voltage			±20	V
	Drain Current -Continuous (Package limited)	T _C = 25 °C		10	
	-Continuous (Silicon limited)	T _C = 25 °C		30	_
ID	-Continuous	T _A = 25 °C	(Note 1a)	12	— A
	-Pulsed			50	
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	12	mJ
D	Power Dissipation	T _C = 25 °C		24	W
P_{D}	Power Dissipation	T _A = 25 °C	(Note 1a)	3.7	VV
T _J , T _{STG}	Operating and Storage Junction Temperature R	ange		-55 to +175	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	6.2	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1a	40	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD6778A	FDD6778A	D-PAK (TO-252)	13 " 12 mm		2500 units

Electrical Characteristics $T_J = 25$ °C unless otherwise noted

Symbol	Parameter	Parameter Test Conditions		Тур	Max	Units
Off Chara	acteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$	25			V
$\frac{\Delta BV_{DS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	I_D = 250 μ A, referenced to 25 °C		17		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 20 V, V _{GS} = 0 V			1	μΑ
I _{GSS}	Gate to Source Leakage Current	V _{GS} = ±20 V, V _{DS} = 0 V			±100	nA

On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	1.0	1.9	3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I _D = 250 μA, referenced to 25 °C		-6		mV/°C
		V _{GS} = 10 V, I _D = 10.0 A		11.4	14	
r _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = 4.5 \text{ V}, I_D = 9.7 \text{ A}$		22.0	30.0	mΩ
		$V_{GS} = 10 \text{ V}, I_D = 10.0 \text{ A}, T_J = 150 ^{\circ}\text{C}$		17.2	21.2	
9 _{FS}	Forward Transconductance	V _{DS} = 5 V, I _D = 10.0 A		33		S

Dynamic Characteristics

C _{iss}	Input Capacitance	V 42.V.V. 0.V.	652	870	pF
C _{oss}	Output Capacitance	$V_{DS} = 13 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1 MHz	142	190	pF
C _{rss}	Reverse Transfer Capacitance	1 - 1 1011 12	129	195	pF
R_g	Gate Resistance		0.8		Ω

Switching Characteristics

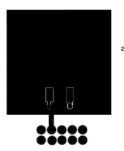
t _{d(on)}	Turn-On Delay Time				6	12	ns
t _r	Rise Time	V _{DD} = 13 V, I _D = 10	$V_{DD} = 13 \text{ V, } I_{D} = 10.0 \text{ A,}$ $V_{GS} = 10 \text{ V, } R_{GEN} = 6 \Omega$		3	10	ns
t _{d(off)}	Turn-Off Delay Time	V _{GS} = 10 V, R _{GEN} =			14	26	ns
t _f	Fall Time				2	10	ns
Q_g	Total Gate Charge	V _{GS} = 0 V to 10 V			12	17	nC
Qg	Total Gate Charge	$V_{GS} = 0 V to 5 V$	V _{DD} = 13 V,		7	10	nC
Q _{gs}	Gate to Source Charge		I _D = 10.0 A		2.0		nC
Q _{gd}	Gate to Drain "Miller" Charge				2.8		nC

Drain-Source Diode Characteristics

V		$V_{GS} = 0 \text{ V}, I_S = 3.1 \text{ A}$ (Note 2)		0.9	1.3	V
V _{SD}	Source to Drain blode Forward voltage	$V_{GS} = 0 \text{ V}, I_{S} = 10.0 \text{ A}$ (Note 2)		0.8	1.2	V
t _{rr}	Reverse Recovery Time	- I _E = 10.0 A, di/dt = 100 A/μs		14	26	ns
Q _{rr}	Reverse Recovery Charge	I _F = 10.0 A, αl/αt = 100 A/μs		3	10	nC

The R_{BJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.

R_{BJC} is guaranteed by design while R_{BJA} is determined by the user's board design.



a) 40 °C/W when mounted on a 1 in² pad of 2 oz copper



b) 96 °C/W when mounted on a minimum pad

- 2: Pulse Test: Pulse Width < 300 μ s, Duty cycle < 2.0%. 3: E_{AS} of 12 mJ is based on starting T_J = 25 °C, L = 1 mH, I_{AS} = 5 A, V_{DD} = 23 V, V_{GS} = 10 V. 100% test at L = 0.1 mH, I_{AS} = 12 A.

Typical Characteristics T_J = 25 °C unless otherwise noted

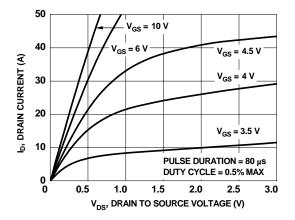


Figure 1. On Region Characteristics

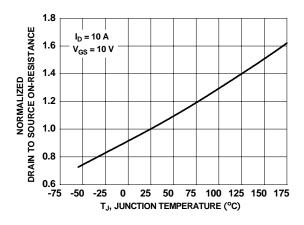


Figure 3. Normalized On Resistance vs Junction Temperature

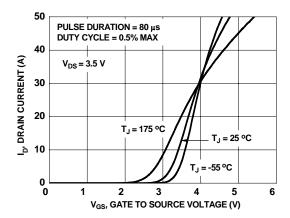


Figure 5. Transfer Characteristics

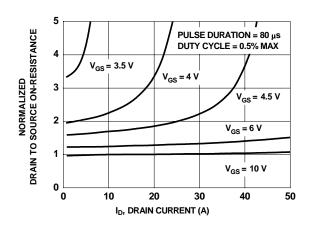


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

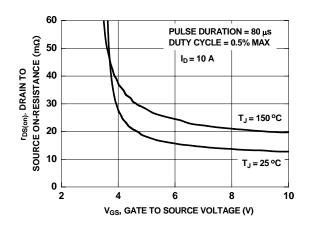


Figure 4. On-Resistance vs Gate to Source Voltage

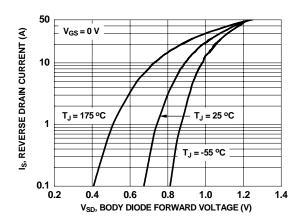


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics $T_J = 25$ °C unless otherwise noted

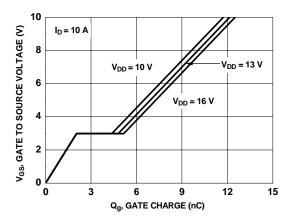


Figure 7. Gate Charge Characteristics

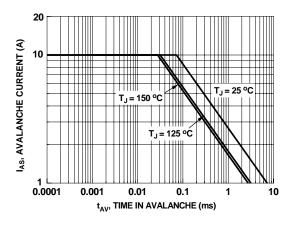


Figure 9. Unclamped Inductive Switching Capability

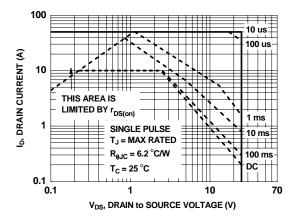


Figure 11. Forward Bias Safe Operating Area

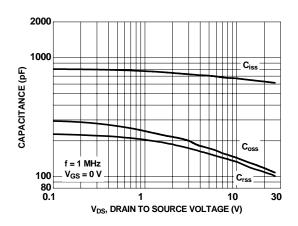


Figure 8. Capacitance vs Drain to Source Voltage

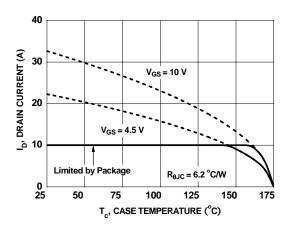


Figure 10. Maximum Continuous Drain Current vs Case Temperature

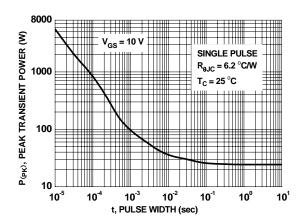


Figure 12. Single Pulse Maximum Power Dissipation

Typical Characteristics $T_J = 25$ °C unless otherwise noted

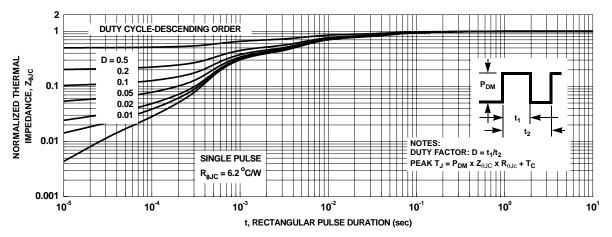


Figure 13. Junction-to-Case Transient Thermal Response Curve

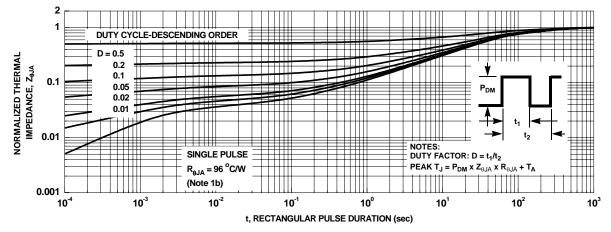


Figure 14. Junction-to-Ambient Transient Thermal Response Curve





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